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Attorney Docket No.: 000939-073311US Client Ref. No.: P01HA010/US

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

On <u>February 23, 2004</u>

TOWNSEND and TOWNSEND and CREW LLP

MAR 0 8 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hong Koo Kim

Application No.: 09/747,779

Filed: December 22, 2000

For: FABRICATION METHOD AND STRUCTURE FOR FERROELECTRIC NONVOLATILE MEMORY FIELD EFFECT TRANSISTOR

Customer No.: 20350

Confirmation No. 4408

Examiner:

Marcos D. Pizarro Crespo

Technology Center/Art Unit: 2814

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action mailed October 21, 2003, please enter the

following amendments and remarks:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 7 of this paper.